NSN 5961-01-164-8418

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-164-8418 **Inclosure Material:** Metal **Overall Length:** 2.320 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-8 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.063 inches **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 700.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 150.00 amperes source cutoff current preset **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: